IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s)	:	Szlufcik, et al.
Appl. No.	:	10/609015
Filed	:	27-Jun-2003
For	:	SEMICONDUCTOR ETCHING PASTE AND THE USE THEREOF FOR LOCALIZED ETCHING OF SEMICONDUCTOR SUBSTRATES
Examiner	:	Unassigned
Group Art Unit :		1765

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

April 29, 2004
(Date)
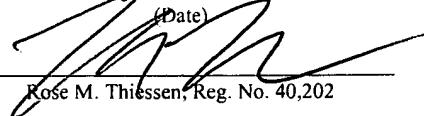
Rose M. Thiessen, Reg. No. 40,202

TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application are:

(X)   An Information Disclosure Statement.

(X)   A PTO Form 1449 with seventeen (17) references.

(X)   The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment, to Account No. 11-1410.

(X)   Return prepaid postcard.

Rose M. Thiessen
Registration No. 40,202
Attorney of Record
Customer No. 20,995
(619) 235-8550
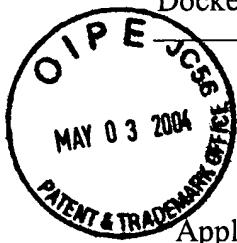
INFORMATION DISCLOSURE STATEMENT

Applicant	:	Szlufcik, et al.
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Examiner	:	Unassigned
Group Art Unit	:	1765

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed is form PTO-1449 listing seventeen (17) references that are also enclosed.

This Information Disclosure Statement is being filed before the receipt of a first Office Action on the merits, and presumably no fee is required in accordance with 37 C.F.R. § 1.97(b)(3). If a first Office Action on the merits was mailed before the mailing date of this Statement, the Commissioner is authorized to charge the fee set forth in 37 C.F.R. § 1.17(p) to Deposit Account No. 11-1410.

Respectfully submitted,

KNOBBE, MARTENS, OLSON & BEAR, LLP
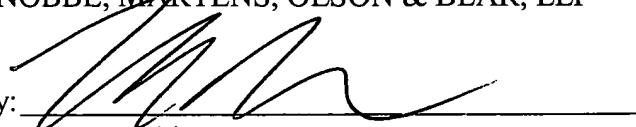
Dated: 4/29/04

By: _____
Rose M. Thiessen
Registration No. 40,202
Attorney of Record
Customer No. 20,995
(619) 235-8550

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FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. IMEC306.001AUS	APPLICATION NO. 10/609,015
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (USE SEVERAL SHEETS IF NECESSARY)	APPLICANT Szlufcik, et al.	
	FILING DATE June 27, 2003	GROUP 1765

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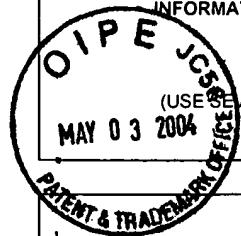
U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
	1	4,605,689	08/12/86	Witheford, et al.			
	2	4,781,792	11/1/88	Hogan			
	3	5,296,043	03/22/94	Kawakami, et al.			
	4	5,461,002	10/24/95	Safir			
	5	5,688,366	11/18/97	Ichinose, et al.			
	6	5,698,451	12/16/97	Hanoka			
	7	5,726,065	03/10/98	Szlufcik, et al.			
	8	5,894,853	04/20/99	Fujisaki, et al.			
	9	5,949,123	09/07/99	Lee, et al.			
	10	6,384,317	05/07/02	Kerschaver, et al.			
	11	6,388,187	05/14/02	Takeyama, et al.			

FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES	TRANSLATION NO
	12	EP0851511A1	07/01/98	Europe				
	13	EP0773590A1	05/14/97	Europe				X
	14	DE3422454A1	12/19/85	Germany				X

EXAMINER INITIAL		OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)
	15	"High throughput laser isolation of crystalline silicon solar cells", G. Emanuel, 17th European Photovoltaic Solar Energy Conference and Exhibition, Munich, Germany, Oct. 22-27, 2001.
	16	"A new passivation method for edge shunts of silicon solar cells", M. Al-Rifai, et al.,17th European Photovoltaic Solar Energy Conference and Exhibition, Munich, Germany, Oct. 22-27, 2001.
	17	European Search Report of EP 03447176.3 dated September 3, 2003.

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EXAMINER	DATE CONSIDERED

*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.